



Photoflash Rectifier

Major Ratings and Characteristics

I _{F(AV)}	500 mA		
V _{RRM}	1600 V		
I _{FSM}	20 A		
V _F	1.5 V		
t _{rr}	300 ns		
T _j max.	175 °C		



Features

- · Glass passivated chip junction
- · Fast switching for high efficiency
- · Low leakage current
- High forward surge capability
- Solder Dip 260 °C, 40 seconds

Pb

Mechanical Data

Case: R-1

Epoxy meets UL-94V-0 Flammability rating

Terminals: Matte tin plated (E3 Suffix) leads, solder-

able per J-STD-002B and JESD22-B102D **Polarity:** Color band denotes cathode end

Typical Applications

For use in high voltage rectification of photoflash application

Maximum Ratings

(T_A = 25 °C unless otherwise noted)

Parameter	Symbol	Value	Unit
Maximum repetitive peak reverse voltage	V_{RRM}	1600	V
Maximum RMS voltage	V _{RMS}	1120	V
Maximum DC blocking voltage	V _{DC}	1600	V
Maximum average forward rectified current 0.375" (9.5 mm) lead length at $T_A = 55\ ^{\circ}C$	I _{F(AV)}	500	mA
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I _{FSM}	20	A
Maximum full load reverse current, full cycle average, 0.375" (9.5 mm) lead length at $T_L = 55\ ^{\circ}C$	I _{R(AV)}	100	μΑ
Operating junction and storage temperature range	T _J , T _{STG}	- 65 to + 175	°C

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Electrical Characteristics

(T_A = 25 °C unless otherwise noted)

Parameter	Test condition	Symbol	Value	Unit
Maximum instantaneous forward voltage drop	at 0.5 A	V_{F}	1.5	V
Maximum DC reverse current at Rated DC blocking voltage	at T _A = 25 °C	I _R	5.0	μΑ
Maximum reverse recovery time	at $I_F = 0.5 \text{ A}$, $I_R = 1.0 \text{ A}$, $I_{rr} = 0.25 \text{ A}$	t _{rr}	300	ns
Typical junction capacitance	at 4.0 V, 1 MHz	СЛ	10	pF

Ratings and Characteristics Curves

(T_A = 25 °C unless otherwise specified)

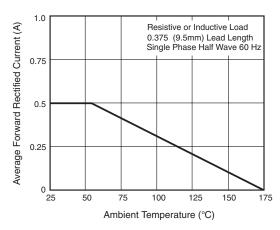


Figure 1. Maximum Forward Current Derating Curve

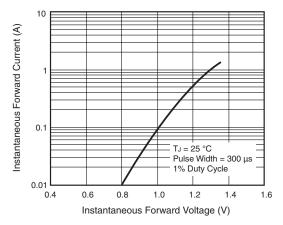


Figure 3. Typical Instantaneous Forward Characteristics

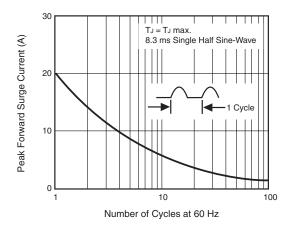


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current

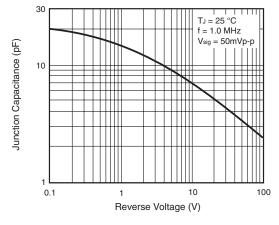


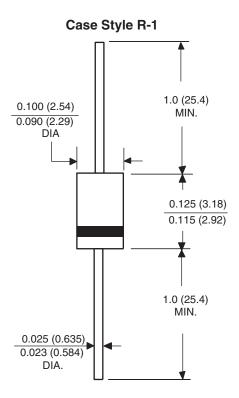
Figure 4. Typical Junction Capacitance

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Package outline dimensions in inches (millimeters)



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